BLF8G10LS-270V; BLF8G10LS-270GV Power LDMOS transistor

AMMPLEON

Rev. 2 — 1 September 2015

Product data sheet

Product profile

1.1 General description

270 W LDMOS power transistor with improved video bandwidth for base station applications at frequencies from 790 MHz to 960 MHz.

Table 1. Typical performance

Typical RF performance at T_{case} = 25 °C in a common source class-AB production test circuit, tested on straight lead device.

Test signal	f	V _{DS}	P _{L(AV)}	Gp	η _D	ACPR _{5M}
	(MHz)	(V)	(W)	(dB)	(%)	(dBc)
2-carrier W-CDMA	869 to 894	28	67	19.5	31	-37 <mark>[1]</mark>

^[1] Test signal: 3GPP test model 1; 64 DPCH; PAR = 8.4 dB at 0.01 % probability on CCDF; carrier spacing 10 MHz.

1.2 Features and benefits

- Excellent ruggedness
- High efficiency
- Low R_{th} providing excellent thermal stability
- Designed for broadband operation (790 MHz to 960 MHz)
- Lower output capacitance for improved performance in Doherty applications
- Decoupling leads to enable improved video bandwidth (55 MHz typical)
- Designed for low memory effects providing excellent pre-distortability
- Internally matched for ease of use
- Integrated ESD protection
- Design optimized for gull-wing and straight lead versions
- Compliant to Directive 2002/95/EC, regarding Restriction of Hazardous Substances (RoHS)

1.3 Applications

RF power amplifiers for W-CDMA base stations and multi carrier applications in the 790 MHz to 960 MHz frequency range

2. Pinning information

Table 2. Pinning

Pin	Description	Simplified outline	Graphic symbol
BLF8G10	LS-270V (SOT1244B)		
1	drain	4 1 5	4
2	gate	4 1 5	6,7
3	source	[1]	2
4	decoupling lead		3
5	decoupling lead		aaa-003619
6	n.c.		
7	n.c.	6 2 7	
BLF8G10	LS-270GV (SOT1244C)		
1	drain	4 1 5	1
2	gate	4 1 5	6,7→1 → 4,5
3	source	<u>[1]</u>	2
4	decoupling lead		- '
5	decoupling lead	6 2 7	aaa-003619
6	n.c.	3	
7	n.c.		

^[1] Connected to flange.

3. Ordering information

Table 3. Ordering information

Type number	Package		
	Name	Description	Version
BLF8G10LS-270V	-	earless flanged ceramic package; 6 leads	SOT1244B
BLF8G10LS-270GV	-	earless flanged ceramic package; 6 leads	SOT1244C

4. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Parameter	Conditions	Min	Max	Unit
drain-source voltage		-	65	V
gate-source voltage		-0.5	+13	V
storage temperature		-65	+150	°C
junction temperature		-	225	°C
	drain-source voltage gate-source voltage storage temperature	drain-source voltage gate-source voltage storage temperature	drain-source voltage - gate-source voltage -0.5 storage temperature -65	drain-source voltage - 65 gate-source voltage -0.5 +13 storage temperature -65 +150

5. Thermal characteristics

Table 5. Thermal characteristics

Symbol	Parameter	Conditions	Тур	Unit
R _{th(j-c)}	thermal resistance from junction to case	T_{case} = 80 °C; P_L = 67 W	0.257	K/W

6. Characteristics

Table 6. DC characteristics

 $T_i = 25$ °C; per section unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{(BR)DSS}	drain-source breakdown voltage	$V_{GS} = 0 \text{ V}; I_D = 4.5 \text{ mA}$	65	-	-	V
$V_{GS(th)}$	gate-source threshold voltage	$V_{DS} = 10 \text{ V}; I_{D} = 450 \text{ mA}$	1.5	1.8	2.3	V
I _{DSS}	drain leakage current	$V_{GS} = 0 \text{ V}; V_{DS} = 28 \text{ V}$	-	-	4.2	μΑ
I _{DSX}	drain cut-off current	$V_{GS} = V_{GS(th)} + 3.75 \text{ V};$ $V_{DS} = 10 \text{ V}$	-	82	-	Α
I _{GSS}	gate leakage current	V _{GS} = 11 V; V _{DS} = 0 V	-	-	420	nΑ
g _{fs}	forward transconductance	V_{DS} = 10 V; I_{D} = 450 mA	-	3.92	-	S
R _{DS(on)}	drain-source on-state resistance	$V_{GS} = V_{GS(th)} + 3.75 V;$ $I_D = 15.75 A$	-	0.04	-	Ω

Table 7. RF characteristics

Test signal: 2-carrier W-CDMA; PAR = 8.4 dB at 0.01 % probability on the CCDF; 3GPP test model 1; 1-64 DPCH; f_1 = 871.5 MHz; f_2 = 881.5 MHz; f_3 = 881.5 MHz; f_4 = 891.5 MHz; f_5 = 881.5 MHz; f_6 = 891.5 MHz; RF performance at V_{DS} = 28 V; I_{Dq} = 2000 mA; T_{case} = 25 °C; unless otherwise specified; in a class-AB production test circuit, tested on straight lead device.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Gp	power gain	$P_{L(AV)} = 67 \text{ W}$	17.3	19.5	-	dB
RLin	input return loss	$P_{L(AV)} = 67 \text{ W}$	-	-16	-12	dB
η_{D}	drain efficiency	$P_{L(AV)} = 67 \text{ W}$	26	31	-	%
ACPR _{5M}	adjacent channel power ratio (5 MHz)	$P_{L(AV)} = 67 \text{ W}$	-	-37	-33	dBc

7. Test information

7.1 Ruggedness in class-AB operation

The BLF8G10LS-270V and BLF8G10LS-270GV are capable of withstanding a load mismatch corresponding to VSWR = 10 : 1 through all phases under the following conditions: V_{DS} = 28 V; I_{Dq} = 2000 mA; P_L = 270 W; f = 820 MHz; f = 869 MHz; f = 920 MHz; f = 960 MHz and a load mismatch corresponding to VSWR = 5 : 1 through all phases under the following conditions: V_{DS} = 28 V; I_{Dq} = 2000 mA; P_L = 270 W; f = 790 MHz.

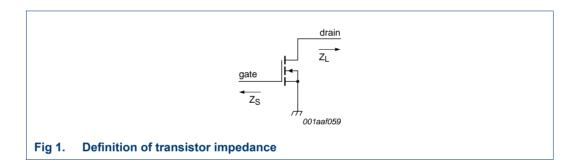
7.2 Impedance information

Table 8. Typical impedance

 $I_{Dq} = 2700 \text{ mA}$; main transistor $V_{DS} = 28 \text{ V}$.

f	Z _S [1]	Z _L [1]
(MHz)	(Ω)	(Ω)
790	1.4 – j1.84	1.22 – j2.07
820	1.58 – j1.96	1.29 – j1.95
869	1.84 – j2.70	1.12 – j1.83
881	1.78 – j2.94	1.12 – j1.84
894	1.90 – j3.08	1.12 – j1.84
920	2.06 - j2.50	1.04 – j1.13
940	2.10 - j2.90	1.04 – j1.13
960	2.56 – j2.65	1.00 – j1.22

[1] Z_S and Z_L defined in Figure 1.



7.3 VBW in class-AB operation

The BLF8G10LS-270V and BLF8G10LS-270GV show 55 MHz (typical) video bandwidth in class-AB test circuit in 800 MHz band at V_{DS} = 28 V and I_{Dq} = 2 A.

7.4 Test circuit

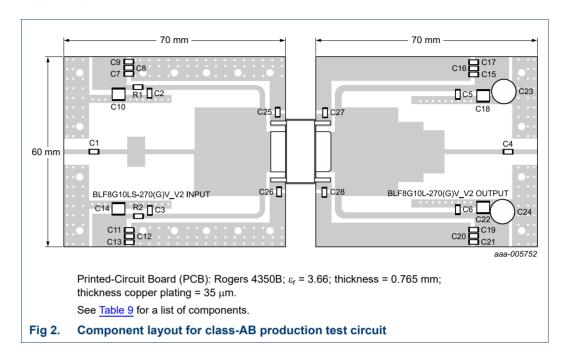


Table 9. List of components For test circuit see Figure 2.

Component	Description	Value		Remarks
C1, C4	multilayer ceramic chip capacitor	47 pF	<u>[1]</u>	ATC100B
C2, C3, C5, C6	multilayer ceramic chip capacitor	45 pF	[1]	ATC100B
C7, C11, C15, C19	multilayer ceramic chip capacitor	0.01 μF	[2]	Murata
C8, C12, C16, C20	multilayer ceramic chip capacitor	0.1 μF	[2]	Murata
C9, C13, C17, C21	multilayer ceramic chip capacitor	1 μF	[2]	Murata
C10, C14, C18, C22	multilayer ceramic chip capacitor	4.7 μF	[2]	Murata
C23, C24	electrolytic capacitor	470 μF, 63 V		
C25, C26, C27, C28	multilayer ceramic chip capacitor	10 μF	[2]	Murata
R1, R2	chip resistor	9.1 Ω	[3]	Vishay Dale 0805

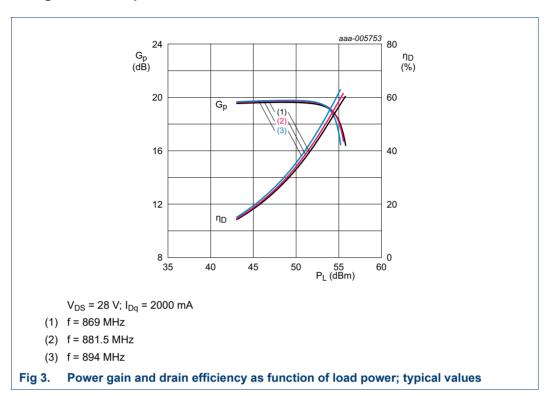
^[1] American Technical Ceramics type 100B or capacitor of same quality.

^[2] Murata or capacitor of same quality.

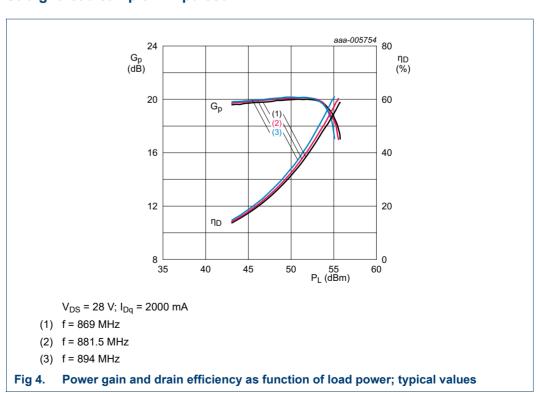
^[3] Vishay Dale resistor of same quality.

7.5 Graphical data

7.5.1 Straight lead sample CW

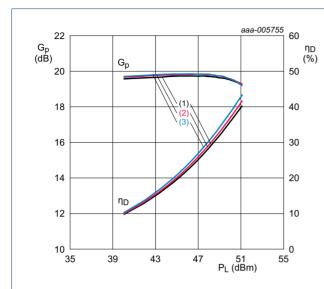


7.5.2 Straight lead sample CW pulsed



BLF8G10LS-270V_8G10LS-270GV#2

7.5.3 Straight lead sample 1-carrier W-CDMA

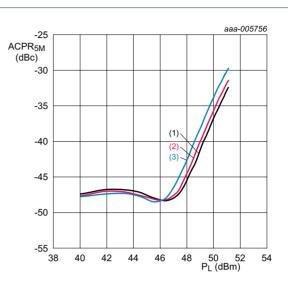


 $V_{DS} = 28 \text{ V}; I_{Dq} = 2000 \text{ mA}$

- (1) f = 869 MHz
- (2) f = 881.5 MHz
- (3) f = 894 MHz

Fig 5. Power gain and drain efficiency as function of load power; typical values

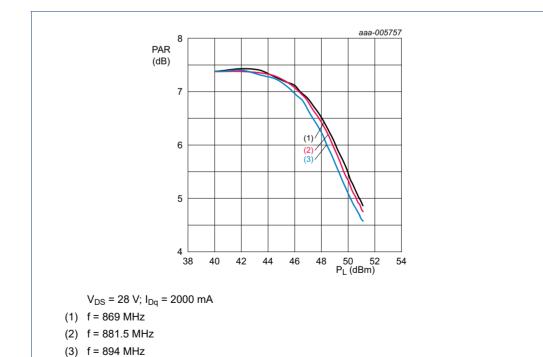
Fig 7.



 $V_{DS} = 28 \text{ V}; I_{Dq} = 2000 \text{ mA}$

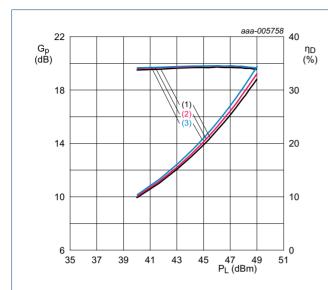
- (1) f = 869 MHz
- (2) f = 881.5 MHz
- (3) f = 894 MHz

Fig 6. Adjacent channel power ratio (5 MHz) as a function of load power; typical values



Peak-to-average ratio as a function of load power; typical values

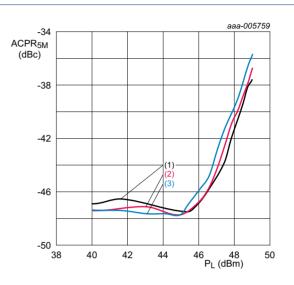
7.5.4 Straight lead sample 2-carrier W-CDMA



 $V_{DS} = 28 \text{ V}; I_{Dq} = 2000 \text{ mA}$

- (1) f = 869 MHz
- (2) f = 881.5 MHz
- (3) f = 894 MHz

Fig 8. Power gain and drain efficiency as function of load power; typical values



 $V_{DS} = 28 \text{ V}; I_{Dq} = 2000 \text{ mA}$

- (1) f = 869 MHz
- (2) f = 881.5 MHz
- (3) f = 894 MHz

Fig 9. Adjacent channel power ratio (5 MHz) as a function of load power; typical values

7.5.5 Gull-wing sample CW

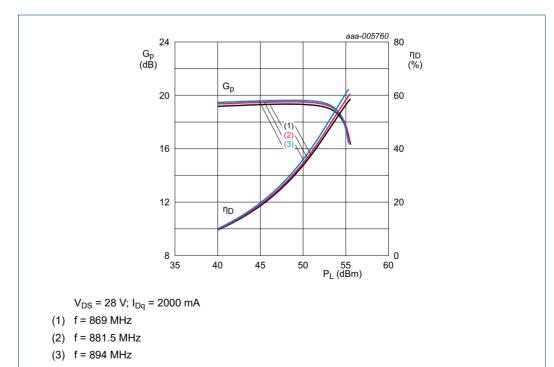
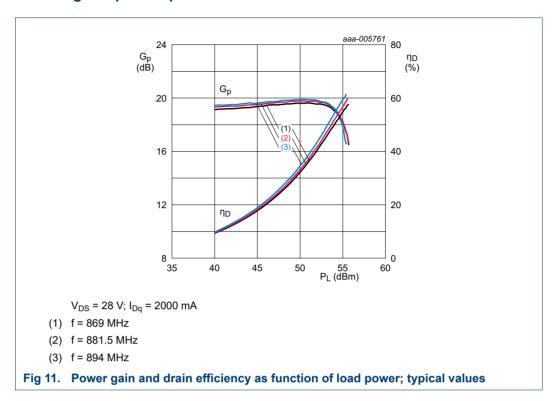
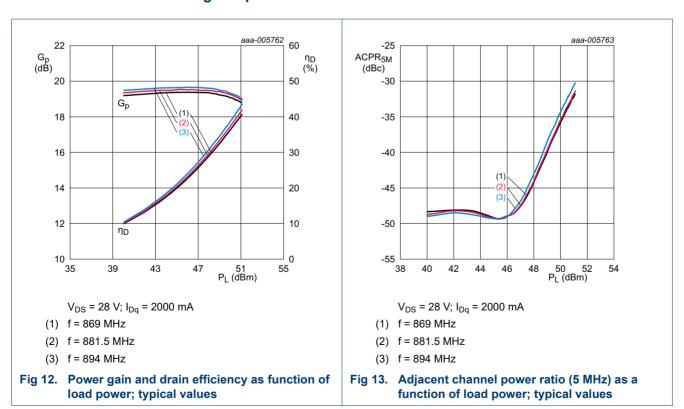


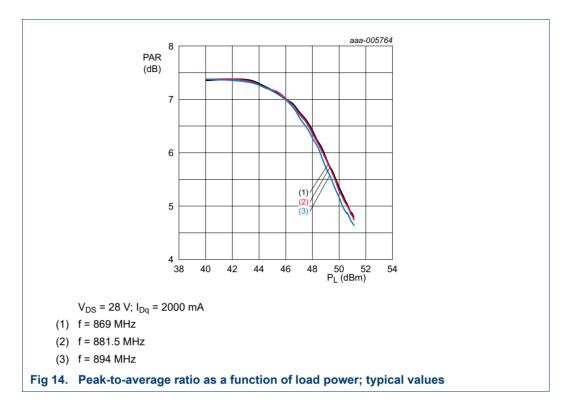
Fig 10. Power gain and drain efficiency as function of load power; typical values

7.5.6 Gull-wing sample CW pulsed

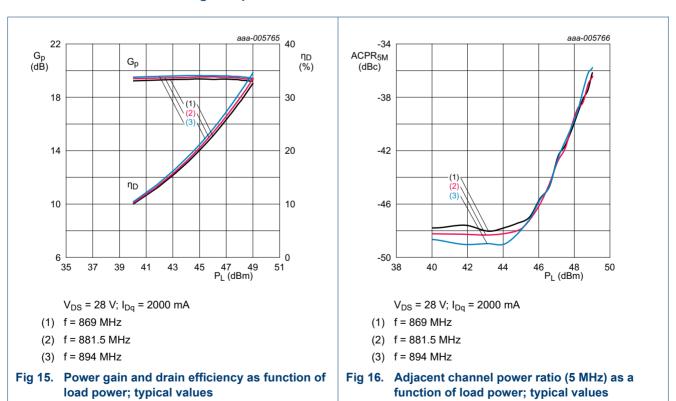


7.5.7 Gull-wing sample 1-carrier W-CDMA

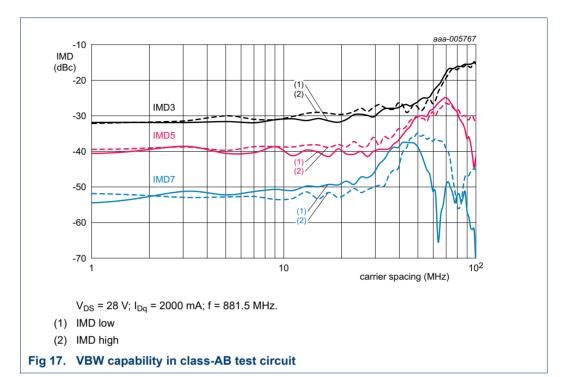




7.5.8 Gull-wing sample 2-carrier W-CDMA



7.5.9 2-Tone VBW



8. Package outline

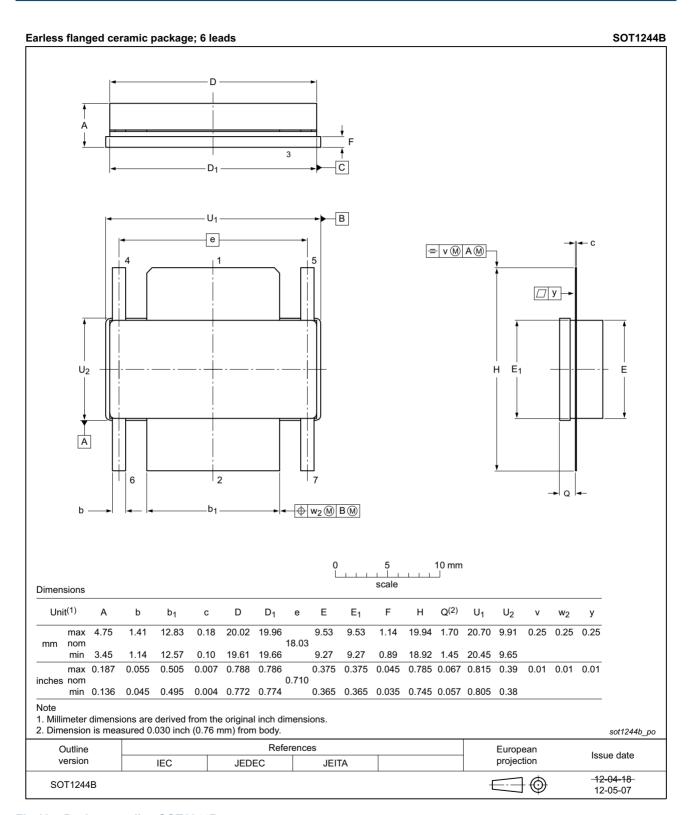


Fig 18. Package outline SOT1244B

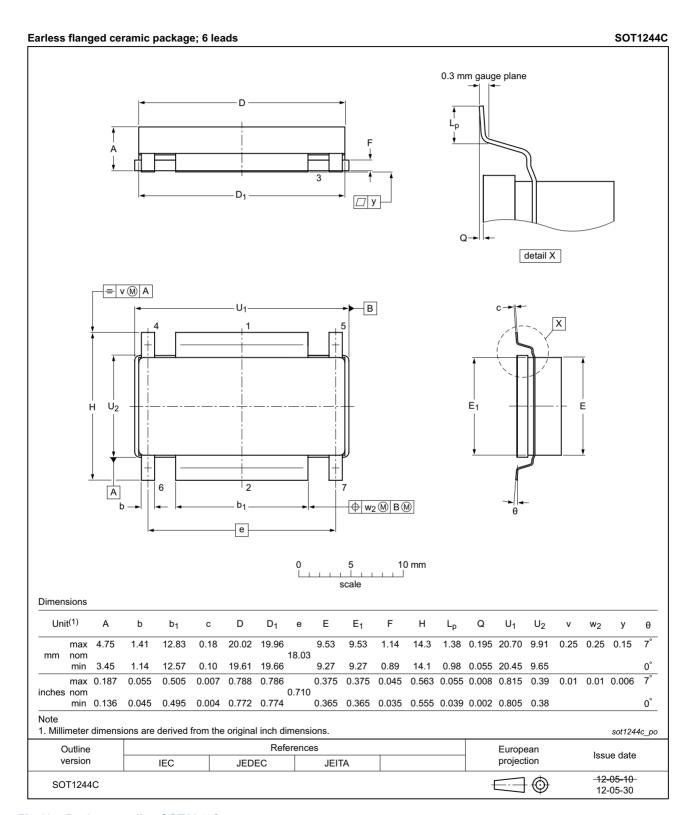


Fig 19. Package outline SOT1244C

9. Handling information

CAUTION



This device is sensitive to ElectroStatic Discharge (ESD). Observe precautions for handling electrostatic sensitive devices.

Such precautions are described in the ANSI/ESD S20.20, IEC/ST 61340-5, JESD625-A or equivalent standards.

10. Abbreviations

Table 10. Abbreviations

Acronym	Description
3GPP	3rd Generation Partnership Project
CCDF	Complementary Cumulative Distribution Function
CW	Continuous Wave
DPCH	Dedicated Physical Channel
ESD	ElectroStatic Discharge
IMD	InterModulation Distortion
LDMOS	Laterally Diffused Metal Oxide Semiconductor
PAR	Peak-to-Average Ratio
VBW	Video BandWidth
VSWR	Voltage Standing Wave Ratio
W-CDMA	Wideband Code Division Multiple Access

11. Revision history

Table 11. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes	
BLF8G10LS-270V_8G10LS-270GV#2	20150901	Product data sheet	-	BLF8G10LS-270V_8G 10LS-270GV v.1	
Modifications:	The format of this document has been redesigned to comply with the new identity guidelines of Ampleon.				
	• Legal texts have been adapted to the new company name where appropriate.				
BLF8G10LS-270V_8G10LS-270GV v.1	20121203	Product data sheet	-	-	

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Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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BLF8G10LS-270(G)V

Power LDMOS transistor

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Power LDMOS transistor

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